



SBOS216B - SEPTEMBER 2001 - REVISED OCTOBER 2006

Low-Power, Single-Supply, CMOS INSTRUMENTATION AMPLIFIERS

FEATURES

- DESIGNED FOR LOW COST
- HIGH GAIN ACCURACY: G = 5, 0.07%, 2ppm/°C
- GAIN SET WITH EXT. RESISTORS FOR > 5V/V
- HIGH CMRR: 73dB DC, 50dB at 45kHz
- LOW BIAS CURRENT: 0.5pA
- BANDWIDTH, SLEW RATE: 2.0MHz, 5V/μs
- RAIL-TO-RAIL OUTPUT SWING: (V+) 0.02V
- WIDE TEMPERATURE RANGE: -55°C to +125°C
- LOW QUIESCENT CURRENT: 490µA max/chan
- SHUTDOWN: 0.01μA
- MSOP-8 SINGLE AND TSSOP-14 DUAL PACKAGES

APPLICATIONS

- INDUSTRIAL SENSOR AMPLIFIERS: Bridge, RTD, Thermocouple, Position
- PHYSIOLOGICAL AMPLIFIERS: ECG, EEG, EMG
- A/D CONVERTER SIGNAL CONDITIONING
- DIFFERENTIAL LINE RECEIVERS WITH GAIN
- FIELD UTILITY METERS
- PCMCIA CARDS
- AUDIO AMPLIFIERS
- COMMUNICATION SYSTEMS
- TEST EQUIPMENT
- AUTOMOTIVE INSTRUMENTATION

DESCRIPTION

The INA332 and INA2332 are rail-to-rail output, low-power CMOS instrumentation amplifiers that offer wide range, singlesupply, and bipolar-supply operation. Using a special manufacturing flow, the INA332 family provides the lowest cost available, while still achieving low-noise amplification of differential signals with low quiescent current of 415 μ A (dropping to 0.01 μ A when shut down). Returning to normal operation within microseconds, this INA can be used for battery or multichannel applications.

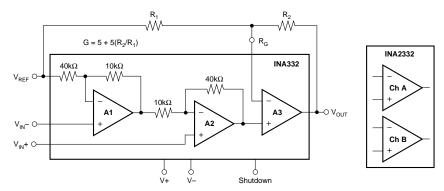
Configured internally in a gain of 5V/V, the INA332 offers flexibility in higher gains by choosing external resistors.

The INA332 rejects line noise and its harmonics because common-mode error remains low even at higher frequencies.

High bandwidth and slew rate make the INA332 ideal for directly driving sampling Analog-to-Digital (A/D) converters as well as general-purpose applications.

With high precision, low cost, and small packages, the INA332 outperforms discrete designs.

Additionally, because they are specified for a wide temperature range of -55° C to $+125^{\circ}$ C, the INA332 family can be used in demanding environments.





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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Supply Voltage, V+ to V	
Signal Input Terminals, Voltage ⁽²⁾	(V–) – 0.5V to (V+) + 0.5V
Current ⁽²⁾	10mA
Output Short-Circuit ⁽³⁾	Continuous
Operating Temperature	–55°C to +125°C
Storage Temperature	–65°C to +150°C
Junction Temperature	

NOTES: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less. (3) Short-circuit to ground, one amplifier per package.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

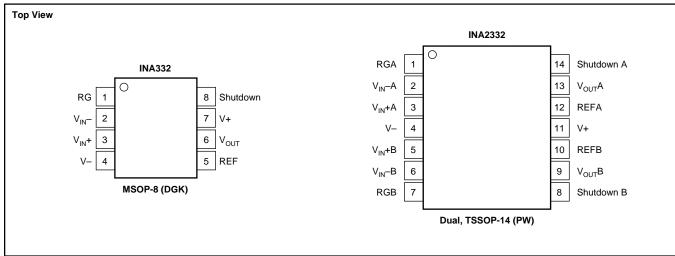
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION⁽¹⁾

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	TEMPERATURE RANGE	SPECIFIED PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
Single INA332AIDGK "	MSOP-8 "	DGK "	–55°C to +125°C "	B32 "	INA332AIDGKT INA332AIDGKR	Tape and Reel, 250 Tape and Reel, 2500
Dual INA2332AIPW "	TSSOP-14 "	PW "	–55°C to +125°C "	2332A "	INA2332AIPWT INA2332AIPWR	Tape and Reel, 250 Tape and Reel, 2500

NOTE: (1) For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or see the TI web site at www.ti.com.

PIN CONFIGURATION



ELECTRICAL CHARACTERISTICS: $V_s = +2.7V$ TO +5.5V

BOLDFACE limits apply over the specified temperature range, $T_A = -55^{\circ}C TO + 125^{\circ}C$

At T_A = +25°C, R_L = 10k Ω , G = 25, and V_{CM} = $V_S/2$, unless otherwise noted.

				INA332AIDGK INA2332AIPW		
PARAMETER		CONDITION	MIN	ТҮР	MAX	UNITS
INPUT						
Input Offset Voltage, RTI		$V_{S} = +5V$		±2	±8	mV
Over Temperature	Vos				±9	mV
	_{os} /dT			±5		μ ν/°C
,	SRR	$V_{S} = +2.7V$ to +5.5V		±50	±250	μV/V
Over Temperature				10.4	±260	μ ν/ν
Long-Term Stability				±0.4 10 ¹³ 3		μV/month
Input Impedance Input Common-Mode Range		V _S = 2.7V	0.35	10.0 3	1.5	Ω pF V
input common-mode rtange		$V_{\rm S} = 5V$	0.55		3.8	v
Common-Mode Rejection C	MRR	$V_{\rm S} = 5V$, $V_{\rm CM} = 0.55V$ to 3.8V	60	73	0.0	dB
Over Temperature		$V_{\rm S} = 5V, V_{\rm CM} = 0.55V$ to 3.8V	60			dB
·		$V_{\rm S} = 2.7$ V, $V_{\rm CM} = 0.35$ V to 1.5V		73		dB
Crosstalk, Dual				114		dB
INPUT BIAS CURRENT		$V_{CM} = V_S/2$				
Bias Current	I _B			±0.5	±10	рА
Offset Current	Ios			±0.5	±10	рА
NOISE, RTI		$R_{S} = 0\Omega$				
Voltage Noise: f = 10Hz	e _N	5		280		nV/√Hz
f = 100Hz				96		nV/√Hz
f = 1kHz				46		nV/√Hz
f = 0.1Hz to $10Hz$				7		μVp-p
Current Noise: f = 1kHz	i _N			0.5		fA/√Hz
GAIN ⁽¹⁾						
Gain Equation, Externally Set		G > 5		$G = 5 + 5(R_2/R_1)$		
Range of Gain			5		1000	V/V
Gain Error				±0.07	±0.4	%
vs Temperature		G = 5		±2	±10	ppm/°C
Nonlinearity Over Temperature		G = 25, V_S = 5V, V_O = 0.05 to 4.95		±0.001 ± 0.002	±0.010 ± 0.015	% of FS % of FS
•				0.002	±0.015	78 01 1 3
OUTPUT Output Voltage Swing from Rail ⁽²⁾		G ≥ 10	50	25		mV
		6 ≥ 10		23		
Over Temperature			50		. (2)	mV
Capacitance Load Drive	.		See	Typical Characteris	(ICS ⁽³⁾	pF
Short-Circuit Current	I _{SC}			+48/-32		mA
FREQUENCY RESPONSE						
Bandwidth, –3dB	BW	G = 25		2.0		MHz
Slew Rate	SR	$V_{\rm S} = 5V, G = 25$		5		V/µs
Settling Time, 0.1% 0.01%	t _S	G = 25, C_L = 100pF, V_O = 2V step		1.7 2.5		μs
Overload Recovery		50% Input Overload G = 25		2.5		μs μs
				-		μο
POWER SUPPLY			107		15 5	v
Specified Voltage Range Operating Voltage Range			+2.7	+2.5 to +5.5	+5.5	V V
Quiescent Current per Channel	Iq	$V_{SD} > 2.5^{(4)}$		415	490	μΑ
Over Temperature	νų	VSD > 2.0		017	430 600	μΑ
Shutdown Quiescent Current/Chan	I _{SD}	$V_{SD} < 0.8^{(4)}$		0.01	1	μΑ
TEMPERATURE RANGE						· ·
Specified/Operating Range			-55		+125	°C
Storage Range			-65		+150	°Č
Thermal Resistance	θ_{JA}	MSOP-8, TSSOP-14 Surface Mount	1	150		°C/W

NOTES: (1) Does not include errors from external gain setting resistors.

(2) Output voltage swings are measured between the output and power-supply rails. Output swings to rail only if G ≥ 10. Output does not swing to positive rail if gain is less than 10.

(3) See typical characteristic curve, Percent Overshoot vs Load Capacitance.

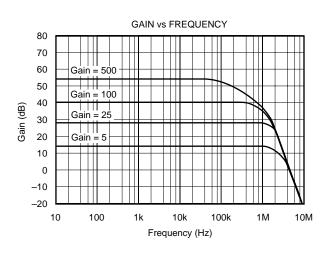
(4) See typical characteristic curve, Shutdown Voltage vs Supply Voltage.

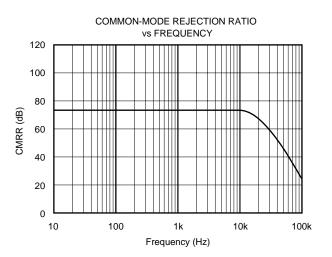


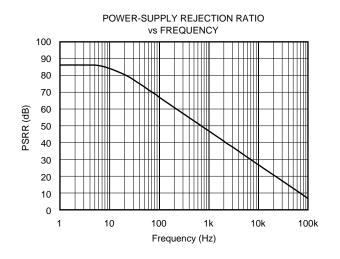


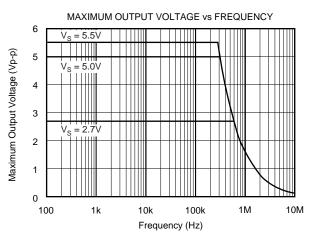
TYPICAL CHARACTERISTICS

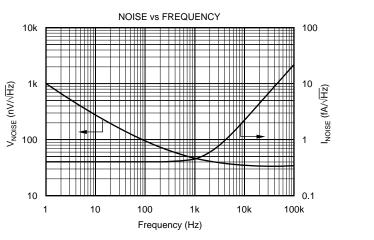
At T_A = +25°C, V_S = 5V, V_{CM} = V_S/2, R_L = 10k Ω , and C_L = 100pF, unless otherwise noted.

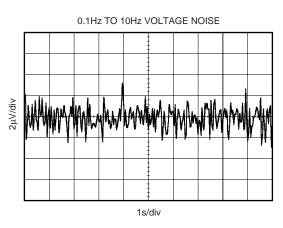




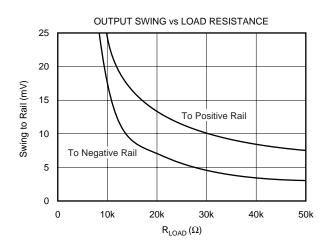








At T_A = +25°C, V_S = 5V, V_{CM} = V_S/2, R_L = 10kΩ, and C_L = 100pF, unless otherwise noted.



QUIESCENT CURRENT AND SHUTDOWN CURRENT

vs POWER SUPPLY

4

Supply Voltage (V)

4.5

5

5.5

ΙQ

 I_{SD}

3.5

3

500

450

400

350

300

250

200

150

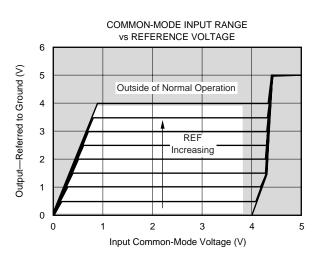
100

50

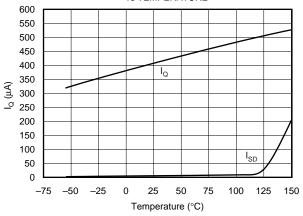
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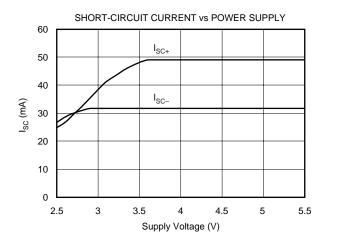
2.5

 I_{Q} (µA), I_{SD} (nA)



QUIESCENT CURRENT AND SHUTDOWN CURRENT vs TEMPERATURE



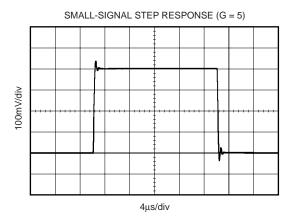


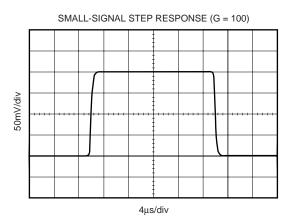
SHORT-CIRCUIT CURRENT vs TEMPERATURE 60 I_{SC+} 50 40 I_{SC-} I_{sc} (mA) 30 20 10 0 -75 -50 -25 0 25 50 75 100 125 150 Temperature (°C)

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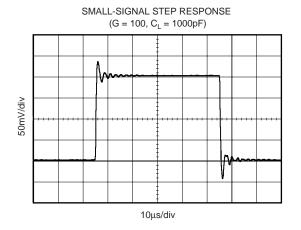


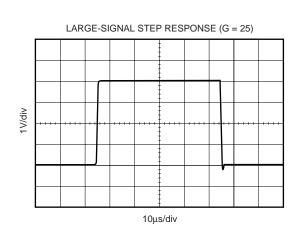
At T_A = +25°C, V_S = 5V, V_{CM} = V_S/2, R_L = 10k Ω , and C_L = 100pF, unless otherwise noted.

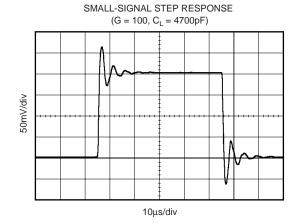




SMALL-SIGNAL STEP RESPONSE $(G = 5, C_L = 1000 pF)$ 100mV/div 4µs/div



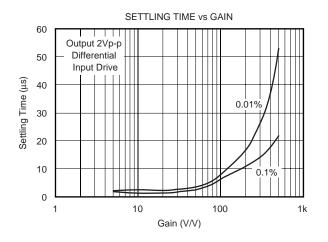


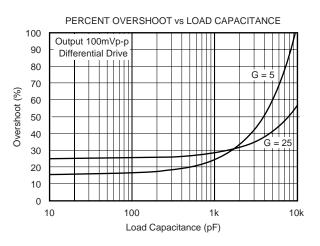


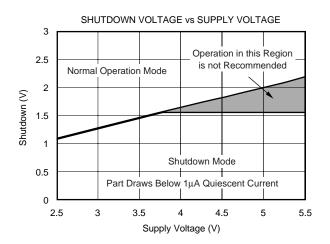


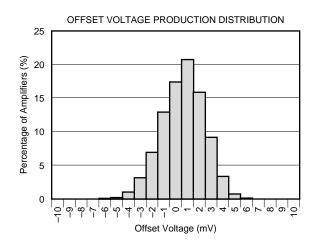
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At T_A = +25°C, V_S = 5V, V_{CM} = V_S/2, R_L = 10kΩ, and C_L = 100pF, unless otherwise noted.

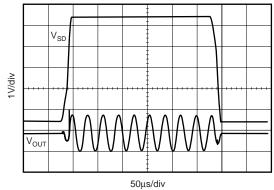


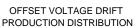


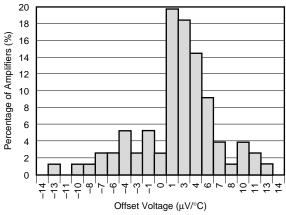




SHUTDOWN TRANSIENT BEHAVIOR



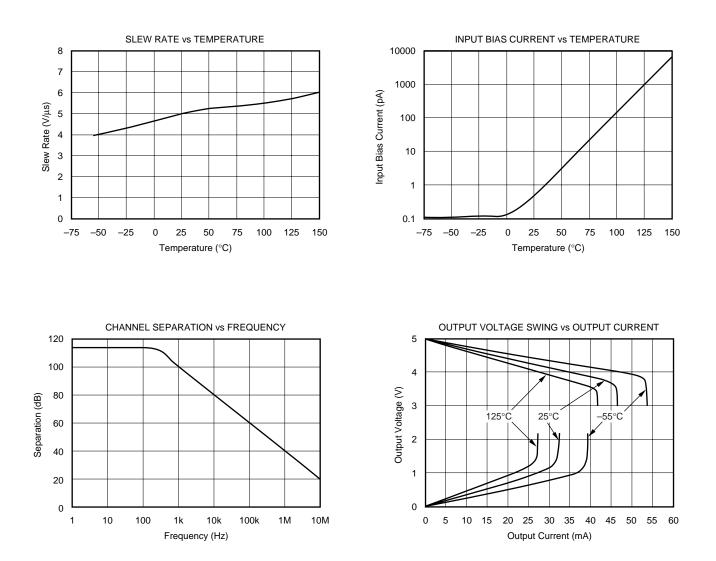








At T_A = +25°C, V_S = 5V, V_{CM} = V_S/2, R_L = 10k Ω , and C_L = 100pF, unless otherwise noted.





APPLICATIONS INFORMATION

The INA332 is a modified version of the classic *two op amp* instrumentation amplifier, with an additional gain amplifier.

Figure 1 shows the basic connections for the operation of the INA332 and INA2332. The power supply should be capacitively decoupled with 0.1μ F capacitors as close to the INA332 as possible for noisy or high-impedance applications.

The output is referred to the reference terminal, which must be at least 1.2V below the positive supply rail.

OPERATING VOLTAGE

The INA332 family is fully specified over a supply range of +2.7V to +5.5V, with key parameters tested over the temperature range of -55° C to +125°C. Parameters that vary significantly with operating conditions, such as load conditions or temperature, are shown in the Typical Characteristics.

The INA332 may be operated on a single supply. Figure 2 shows a bridge amplifier circuit operated from a single +5V supply. The bridge provides a small differential voltage riding on an input common-mode voltage.

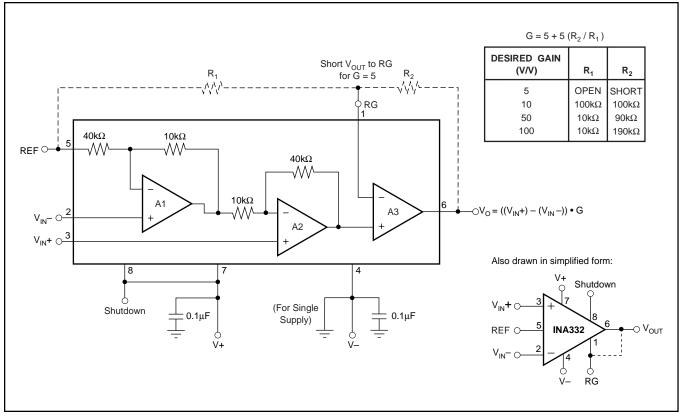


FIGURE 1. Basic Connections.

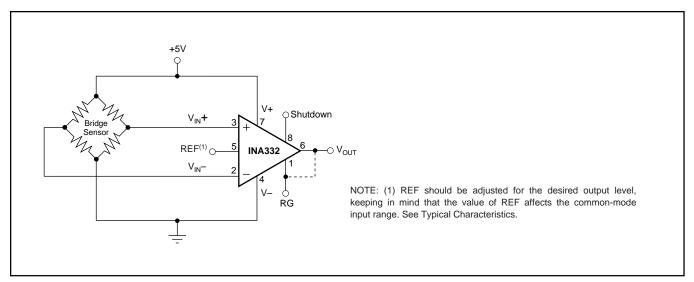


FIGURE 2. Single-Supply Bridge Amplifier.



SETTING THE GAIN

The ratio of R_2 to R_1 , or the impedance between pins 1, 5, and 6, determines the gain of the INA332. With an internally set gain of 5, the INA332 can be programmed for gains greater than 5 according to the following equation:

$$G = 5 + 5 (R_2/R_1)$$

The INA332 is designed to provide accurate gain, with gain error less than 0.4%. Setting gain with matching TC resistors will minimize gain drift. Errors from external resistors will add directly to the error, and may become dominant error sources.

COMMON-MODE INPUT RANGE

The upper limit of the common-mode input range is set by the common-mode input range of the second amplifier, A2, to 1.2V below positive supply. Under most conditions, the amplifier operates beyond this point with reduced performance. The lower limit of the input range is bounded by the output swing of amplifier A1, and is a function of the reference voltage according to the following equation:

$$V_{OA1} = 5/4 V_{CM} - 1/4 V_{REF}$$

(See typical characteristic curve, *Common-Mode Input Range* vs Reference Voltage).

REFERENCE

The reference terminal defines the zero output voltage level. In setting the reference voltage, the common-mode input of A3 should be considered according to the following equation:

$$V_{OA2} = V_{REF} + 5 (V_{IN} + - V_{IN} -)$$

For ensured operation, V_{OA2} should be less than V_{DD} – 1.2V.

The reference pin requires a low-impedance connection. As little as 160Ω in series with the reference pin will degrade the CMRR to 50dB. The reference pin may be used to compensate for the offset voltage (see the *Offset Trimming* section). The reference voltage level also influences the common-mode input range (see the *Common-Mode Input Range* section).

INPUT BIAS CURRENT RETURN

With a high input impedance of $10^{13}\Omega$, the INA332 is ideal for use with high-impedance sources. The input bias current of less than 10pA makes the INA332 nearly independent of input impedance and ideal for low-power applications. For proper operation, a path must be provided for input bias currents for both inputs. Without input bias current paths, the inputs will *float* to a potential that exceeds common-mode range and the input amplifier will saturate. Figure 3 shows how bias current path can be provided in the cases of microphone applications, thermistor applications, ground returns, and dc-coupled resistive bridge applications.

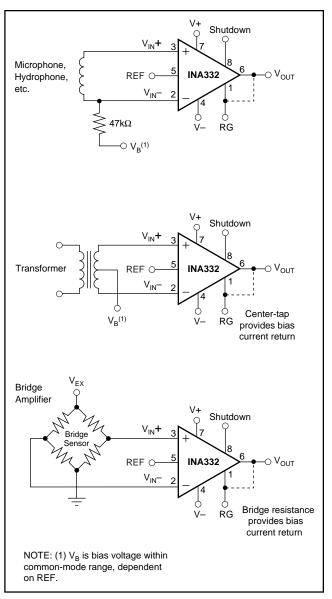


FIGURE 3. Providing an Input Common-Mode Path.

When differential source impedance is low, the bias current return path can be connected to one input. With higher source impedance, two equal resistors will provide a balanced input. The advantages are lower input offset voltage due to bias current flowing through the source impedance and better high-frequency gain.



SHUTDOWN MODE

The shutdown pin of the INA332 is nominally connected to V+. When the pin is pulled below 0.8V on a 5V supply, the INA332 goes into sleep mode within nanoseconds. For actual shutdown threshold, see typical characteristic curve, *Shutdown Voltage vs Supply Voltage*. Drawing less than 2μ A of current, and returning from sleep mode in microseconds, the shutdown feature is useful for portable applications. Once in sleep mode, the amplifier has high output impedance, making the INA332 suitable for multiplexing.

RAIL-TO-RAIL OUTPUT

A class AB output stage with common-source transistors is used to achieve rail-to-rail output for gains of 10 or greater. For resistive loads greater than $10k\Omega$, the output voltage can swing to within 25mV of the supply rail while maintaining low gain error. For heavier loads and over temperature, see the typical characteristic curve, *Output Voltage Swing vs Output Current*. The INA332's low output impedance at high frequencies makes it suitable for directly driving Capacitive-Input A/D converters, as shown in Figure 4.

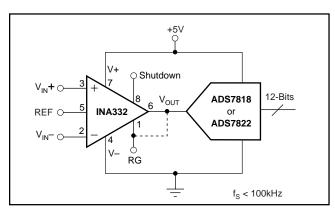


FIGURE 4. INA332 Directly Drives Capacitive-Input, High-Speed A/D Converter.

OUTPUT BUFFERING

The INA332 is optimized for a load impedance of $10k\Omega$ or greater. For higher output current the INA332 can be buffered using the OPA340, as shown in Figure 5. The OPA340 can swing within 50mV of the supply rail, driving a 600Ω load. The OPA340 is available in the tiny MSOP-8 package.

OFFSET TRIMMING

The INA332 is laser trimmed for low offset voltage. In the event that external offset adjustment is required, the offset can be adjusted by applying a correction voltage to the reference terminal. Figure 6 shows an optional circuit for trimming offset voltage. The voltage applied to the REF terminal is added to the output signal. The gain from REF to V_{OUT} is +1. An op amp buffer is used to provide low impedance at the REF terminal to preserve good common-mode rejection.

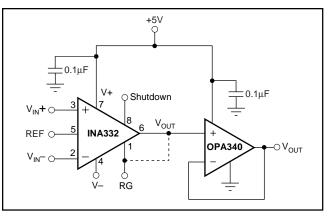


FIGURE 5. Output Buffering Circuit. Able to drive loads as low as 600Ω .

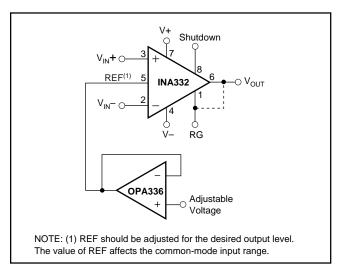


FIGURE 6. Optional Offset Trimming Voltage.

INPUT PROTECTION

Device inputs are protected by ESD diodes that will conduct if the input voltages exceed the power supplies by more than 500mV. Momentary voltages greater than 500mV beyond the power supply can be tolerated if the current through the input pins is limited to 10mA. This is easily accomplished with input resistor R_{LIM}, as shown in Figure 7. Many input signals are inherently current-limited to less than 10mA; therefore, a limiting resistor is not required.

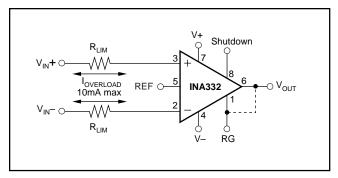


FIGURE 7. Sample Output Buffering Circuit.

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OFFSET VOLTAGE ERROR CALCULATION

The offset voltage (V_{OS}) of the INA332AIDGK is specified at a maximum of 500 μ V with a +5V power supply and the common-mode voltage at V_S/2. Additional specifications for power-supply rejection and common-mode rejection are provided to allow the user to easily calculate worst-case expected offset under the conditions of a given application.

Power-Supply Rejection Ratio (PSRR) is specified in μ V/V. For the INA332, worst case PSRR is 200 μ V/V, which means for each volt of change in power supply, the offset may shift up to 200 μ V. Common-Mode Rejection Ratio (CMRR) is specified in dB, which can be converted to μ V/V using the following equation:

CMRR (in μ V/V) = 10^[(CMRR in dB)/-20] • 10⁶

For the INA332, the worst case CMRR over the specified common-mode range is 60dB (at G = 25) or about 30μ V/V This means that for every volt of change in common-mode, the offset will shift less than 30μ V.

These numbers can be used to calculate excursions from the specified offset voltage under different application conditions. For example, an application might configure the amplifier with a 3.3V supply with 1V common-mode. This configuration varies from the specified configuration, representing a 1.7V variation in power supply (5V in the offset specification versus 3.3V in the application) and a 0.65V variation in common-mode voltage from the specified V_S/2.

Calculation of the worst-case expected offset would be as follows:

Adjusted V_{OS} = Maximum specified V_{OS} + (power-supply variation) • PSRR + (common-mode variation) • CMRR

 $V_{OS} = 0.5mV + (1.7V \bullet 200\mu V) + (0.65V \bullet 30\mu V)$ = ±0.860mV

However, the typical value will be smaller, as seen in the Typical Characteristics.

FEEDBACK CAPACITOR IMPROVES RESPONSE

For optimum settling time and stability with high-impedance feedback networks, it may be necessary to add a feedback capacitor across the feedback resistor, R_F , as shown in Figure 8. This capacitor compensates for the zero created by the feedback network impedance and the INA332's RG-pin input capacitance (and any parasitic layout capacitance). The effect becomes more significant with higher impedance networks. Also, R_X and C_L can be added to reduce high-frequency noise.

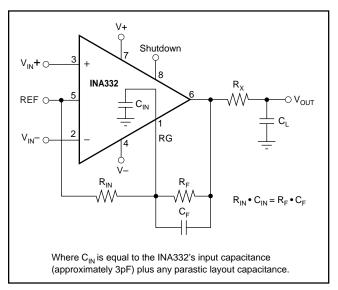


FIGURE 8. Feedback Capacitor Improves Dynamic Performance.

It is suggested that a variable capacitor be used for the feedback capacitor since input capacitance may vary between instrumentation amplifiers, and layout capacitance is difficult to determine. For the circuit shown in Figure 8, the value of the variable feedback capacitor should be chosen by the following equation:

$$\mathsf{R}_{\mathsf{IN}} \bullet \mathsf{C}_{\mathsf{IN}} = \mathsf{R}_{\mathsf{F}} \bullet \mathsf{C}_{\mathsf{F}}$$

Where C_{IN} is equal to the INA332's RG-pin input capacitance (typically 3pF) plus the layout capacitance. The capacitor can be varied until optimum performance is obtained.

APPLICATION CIRCUITS

MEDICAL ECG APPLICATIONS

Figure 9 shows the INA332 configured to serve as a low-cost ECG amplifier, suitable for moderate accuracy heart-rate applications such as fitness equipment. The input signals are obtained from the left and right arms of the patient. The common-mode voltage is set by two $2M\Omega$ resistors. This potential through a buffer provides optional right leg drive.

Filtering can be modified to suit application needs by changing the capacitor value of the output filter.

LOW-POWER, SINGLE-SUPPLY DATA ACQUISITION SYSTEMS

Refer to Figure 4 to see the INA332 configured to drive an ADS7818. Functioning at frequencies of up to 500kHz, the INA332 is ideal for low-power data acquisition.

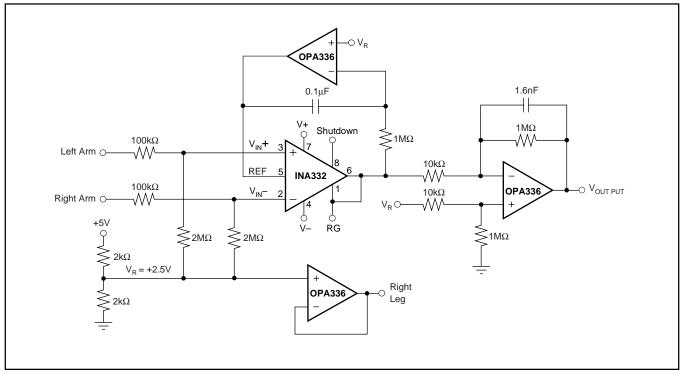


FIGURE 9. Simplified ECG Circuit for Medical Applications.





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
INA2332AIPWR	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	INA 2332A	Samples
INA2332AIPWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	INA 2332A	Samples
INA2332AIPWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	INA 2332A	Samples
INA332AIDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	B32	Samples
INA332AIDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	B32	Samples
INA332AIDGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	B32	Samples
INA332AIDGKTG4	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	B32	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

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⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA2332AIPWR	TSSOP	PW	14	2500	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
INA2332AIPWT	TSSOP	PW	14	250	180.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
INA332AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA332AIDGKT	VSSOP	DGK	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA2332AIPWR	TSSOP	PW	14	2500	367.0	367.0	35.0
INA2332AIPWT	TSSOP	PW	14	250	210.0	185.0	35.0
INA332AIDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
INA332AIDGKT	VSSOP	DGK	8	250	210.0	185.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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